

The MOCVD Challenge

Volume 1: A Survey of GaInAsP–InP for Photonic and Electronic Applications

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Contents

Foreword	ix
Preface	xi
Introduction	1
1 Growth Technology	3
1.1 Introduction	3
1.2 Metallorganic chemical vapour deposition	8
1.3 New non-equilibrium growth techniques	24
References	28
2 InP–InP System: MOCVD Growth, Characterization and Application	29
2.1 Introduction	29
2.2 Energy band structure of InP	29
2.3 Growth and characterization of InP using TEIn	32
2.4 Growth and characterization of InP using TMIn	51
2.5 Incorporation of dopants	57
2.6 Application of InP epitaxial layers	63
References	67
3 GaInAs–InP System: MOCVD Growth, Characterization and Application	69
3.1 Growth conditions	69
3.2 Optical and crystallographic properties, and impurity incorporation of GaInAs grown by MOCVD	76
3.3 Shallow p ⁺ layers in GaInAs grown by MOCVD by Hg implantation	96
3.4 GaInAs–InP heterojunctions, multiquantum wells and superlattices grown by MOCVD	99

3.5	Magnetotransport in GaInAs–InP heterojunctions grown by MOCVD	117
3.6	Applications of GaInAs–InP systems grown by MOCVD	153
	References	159
4	GaInAsP–InP System: MOCVD Growth, Characterization and Application	165
4.1	Growth conditions	165
4.2	Characterization	173
4.3	Applications of GaInAsP–InP systems grown by MOCVD	204
	References	259
5	MOCVD Growth, Characterization and Applications of III–V Semiconductor Strained Heterostructures	263
5.1	Growth procedure and characterization	263
5.2	Growth of GaInAs–InP multiquantum wells on Gd ₃ Ga ₅ O ₁₂ garnet (GGG) substrate	269
5.3	Applications	275
5.4	Monolayer epitaxy of (GaAs) _n (InAs) _n –InP by MOCVD	284
	References	289
6	MOCVD Growth of III–V Heterojunctions and Superlattices on Si Substrates and their Applications	290
6.1	Introduction	290
6.2	MOCVD growth of GaAs on Si	294
6.3	InP grown on Si	296
6.4	GaInAsP–InP grown on Si	300
6.5	Applications	304
	References	319
	Appendix Safety Information about Alkyls	321
	Index	327